## NSN 5962-01-372-6878

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-372-6878

Body Length:
1.060 inches
Body Width:
0.200 inches
Body Height:
0.310 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
7p blk 2 dcn, e/i fscm 49956
Features Provided:
Programmable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, memory, 16-input 4-output registered and-or gate array
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification

format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain

standard (includes industry or association standards, individual manufactureer standards, etc.).

environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883

Terminal Type And Quantity:

## NSN 5962-01-372-6878

Memory Microcircuit - Page 2 of 2



Spec	ific	ation	Data:
------	------	-------	-------

67268-5962-85155 government standard

## **Specification Or Standard:**

16 type and r case and a finish

Shelf Life:

N/a

**Unit Of Measure:** 

\_\_

Demilitarization:

Yes - demil/mli

Fiig:

A458a0